# **BD159G**

# **Plastic Medium-Power Silicon NPN Transistor**

This device is designed for power output stages for television, radio, phonograph and other consumer product applications.

# **Features**

- Suitable for Transformerless, Line-Operated Equipment
- High Power Dissipation Rating for High Reliability
- These Devices are Pb-Free and are RoHS Compliant\*

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	350	Vdc
Collector-Base Voltage	V <sub>CB</sub>	375	Vdc
Emitter-Base Voltage	V <sub>EB</sub>	5.0	Vdc
Collector Current - Continuous	I <sub>C</sub>	0.5	Adc
Collector Current - Peak	I <sub>CM</sub>	1.0	Adc
Base Current	Ι <sub>Β</sub>	0.25	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	20 0.16	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

# THERMAL CHARACTERISTICS

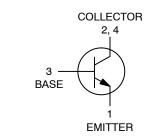
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	6.25	°C/W



# ON Semiconductor®

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# 0.5 AMPERE **POWER TRANSISTOR NPN SILICON 350 VOLTS, 20 WATTS**





# **MARKING DIAGRAM**



= Year WW = Work Week BD159 = Device Code = Pb-Free Package

# **ORDERING INFORMATION**

Device	Package	Shipping
BD159G	TO-225 (Pb-Free)	500 Units/Box

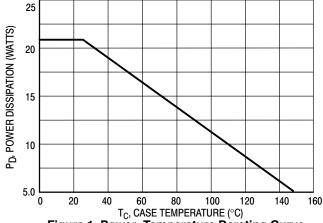
<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

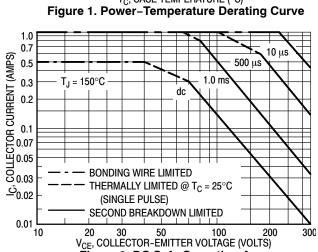
1

**ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage (I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0)	BV <sub>CEO</sub>	350	-	Vdc
Collector Cutoff Current (at rated voltage)	I <sub>CBO</sub>	-	100	μAdc
Emitter Cutoff Current (V <sub>EB</sub> = 5.0 Vdc, I <sub>C</sub> = 0)	I <sub>EBO</sub>	-	100	μAdc
ON CHARACTERISTICS				
DC Current Gain (I <sub>C</sub> = 50 mAdc, V <sub>CE</sub> = 10 Vdc)	h <sub>FE</sub>	30	240	-

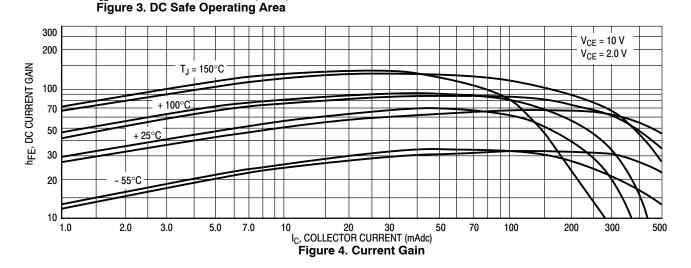
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.





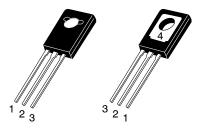
 $V_{BE} @ I_{C}/I_{B} = 10$ 0.8 V, VOLTAGE (VOLTS) V<sub>BE</sub> @ V<sub>CE</sub> = 10 V  $V_{CE(sat)} @ I_C/I_B = 10$ 0.2 +25°C  $I_{C}/I_{B} = 5.0$ 0 30 50 100 I<sub>C</sub>, COLLECTOR CURRENT (mA) 20 10 200 300 500 Figure 2. "On" Voltages

The Safe Operating Area Curves indicate  $I_C - V_{CE}$  limits below which the device will not enter secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a catastrophic failure. To insure operation below, the maximum  $T_J$ , power–temperature derating must be observed for both steady state and pulse power conditions.



## **BD159G**

## PACKAGE DIMENSIONS



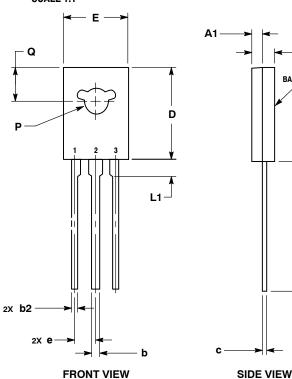
TO-225 CASE 77-09 **ISSUE AD** 

PIN 4 BACKSIDE TAB

**FRONT VIEW** 

**BACK VIEW** 

SCALE 1:1



- NOTES:

  1. DIMENSIONING AND TOLERANCING PER
  ASME Y14.5M, 1994.

  2. CONTROLLING DIMENSION: MILLIMETERS.

  3. NUMBER AND SHAPE OF LUGS OPTIONAL.

	MILLIMETERS		
DIM	MIN	MAX	
Α	2.40	3.00	
A1	1.00	1.50	
b	0.60	0.90	
b2	0.51	0.88	
C	0.39	0.63	
D	10.60	11.10	
Е	7.40	7.80	
е	2.04	2.54	
L	14.50	16.63	
L1	1.27	2.54	
P	2.90	3.30	
Q	3.80	4.20	

STYLE 1:

PIN 1. EMITTER COLLECTOR 2., 4.

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